

MiniSKiiP®0

3-phase bridge rectifier + 3-phase bridge inverter

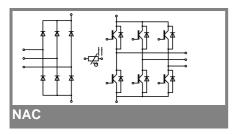
SKiiP 02NAC12T4V1

#### **Features**

- Trench 4 IGBTs
- · Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E 63532

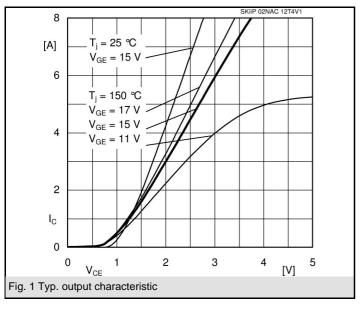
#### Remarks

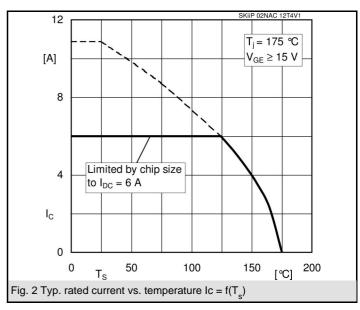
- V<sub>CEsat</sub>, V<sub>F</sub>= chip level value
  Case temp. limited to T<sub>C</sub> = 125°C max. (for baseplateless modules  $T_C = T_S$
- product rel. results valid for  $T_i \le 150$  (recomm.  $T_{op} = -40$  ...
- Temp.Sensor: No basic insulaton to main circuit, max. potential difference 850V to -DC

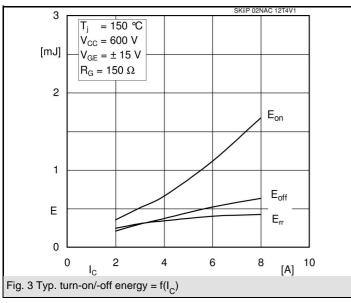


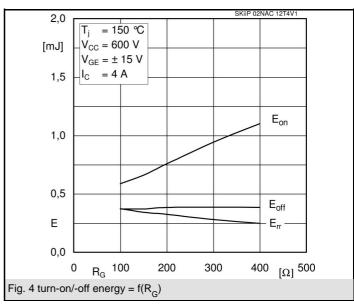
<b>Absolute Maximum Ratings</b> $T_S = 25  ^{\circ}\text{C}$ , unless otherwise specified							
Symbol	Conditions	Values	Units				
IGBT - Inverter							
$V_{CES}$		1200	V				
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	6 (6)	Α				
I <sub>CRM</sub>		12	Α				
$V_{GES}$		± 20	V				
T <sub>j</sub>		-40+175	°C				
Diode - Inverter							
I <sub>F</sub>	T <sub>s</sub> = 25 (70) °C	7,5 (7,5)	Α				
I <sub>FRM</sub>		24	Α				
T <sub>j</sub>		-40+175	°C				
Diode - Rectifier							
$V_{RRM}$		1600	V				
I <sub>F</sub>	T <sub>s</sub> = 70 °C	35	Α				
I <sub>FSM</sub>	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_i = 25 ^\circ\text{C}$	220	Α				
i²t	$t_{\rm p}$ = 10 ms, sin 180 °, $T_{\rm i}$ = 25 °C	240	A²s				
T <sub>j</sub>	,	-40+150	°C				
Module							
I <sub>tRMS</sub>	per power terminal (20 A / spring)	20	Α				
T <sub>stg</sub>		-40+125	°C				
V <sub>isol</sub>	AC, 1 min.	2500	V				

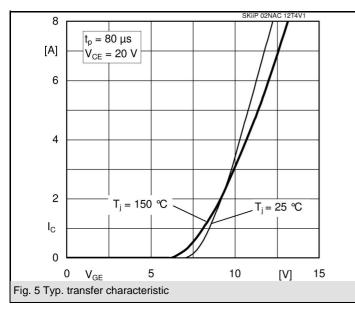
Characte	ristics	T <sub>S</sub> = 25 °C, unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Inverter								
$V_{CEsat}$	$I_{Cnom} = 4 \text{ A}, T_j = 25 (150) ^{\circ}\text{C}$		1,85 (2,25)	2,05 (2,45)	V			
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}$ , $I_{C} = 1 \text{ mA}$	5	5,8	6,5	V			
V <sub>CE(TO)</sub>	$T_j = 25 (150)  ^{\circ}C$		0,8 (0,7)	,	V			
r <sub>T</sub>	$T_j = 25 (150)  ^{\circ}C$		260 (390)	290 (410)	mΩ			
C <sub>ies</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,25		nF			
C <sub>oes</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,025		nF			
C <sub>res</sub>	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,015		nF			
$R_{th(j-s)}$	per IGBT		2,49		K/W			
t <sub>d(on)</sub>	under following conditions		65		ns			
t <sub>r</sub>	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		45		ns			
t <sub>d(off)</sub>	$I_{Cnom} = 4 \text{ A}, T_j = 150^{\circ}\text{C}$		300		ns			
t <sub>f</sub>	$R_{Gon} = R_{Goff} = 150 \Omega$		110		ns			
Ė <sub>on</sub>	inductive load		0,66		mJ			
E <sub>off</sub>			0,37		mJ			
Diode - Inverter								
$V_F = V_{EC}$	I <sub>Fnom</sub> = 4 A, T <sub>i</sub> = 25 (150) °C		2,05 (1,85)	2,35 (2,15)	V			
$V_{(TO)}$	T <sub>i</sub> = 25 (150) °C			1,45 (1,05)	V			
r <sub>T</sub>	$T_j = 25 (150)  ^{\circ}C$		200 (250)	225 (275)	mΩ			
$R_{th(j-s)}$	per diode		2,53		K/W			
I <sub>RRM</sub>	under following conditions		3,4		Α			
$Q_{rr}$	$I_{Fnom} = 4 \text{ A}, V_{R} = 600 \text{ V}$		0,95		μC			
E <sub>rr</sub>	$V_{GE} = 0 \text{ V}, T_j = 150 ^{\circ}\text{C}$		0,34		mJ			
	$di_F/dt = 110 A/\mu s$							
Diode - Rectifier								
$V_{F}$	I <sub>Fnom</sub> = 15 A, T <sub>i</sub> = 25 °C		1,1		V			
V <sub>(TO)</sub>	T <sub>i</sub> = 150 °C		0,8		V			
r <sub>T</sub>	T <sub>i</sub> = 150 °C		20		mΩ			
R <sub>th(j-s)</sub>	per diode		1,5		K/W			
	ure Sensor							
R <sub>ts</sub>	3 %, T <sub>r</sub> = 25 (100) °C		1000(1670)		Ω			
Mechanical Data								
w			20		g			
$M_s$	Mounting torque	2		2,5	Nm			

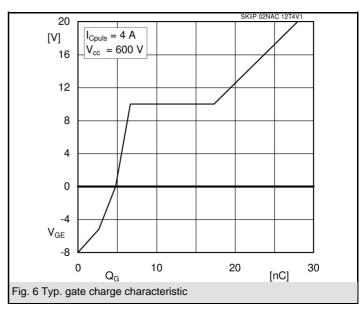


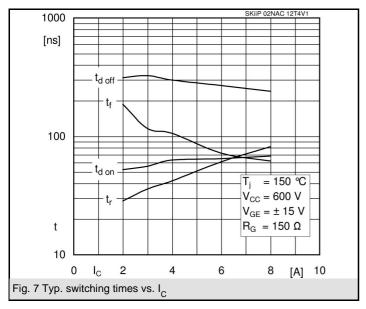


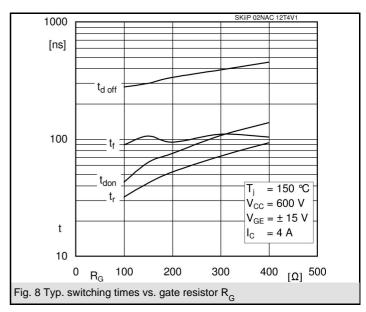


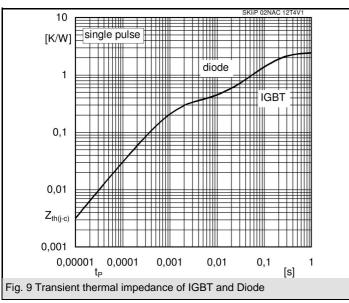


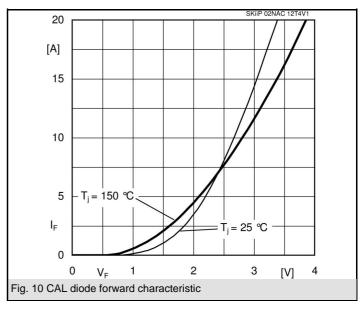


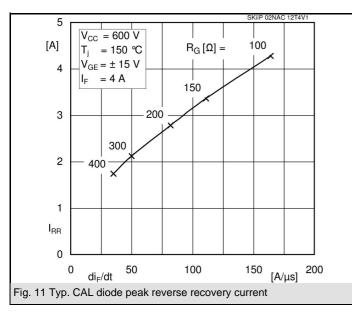


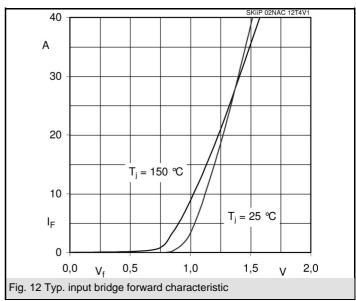


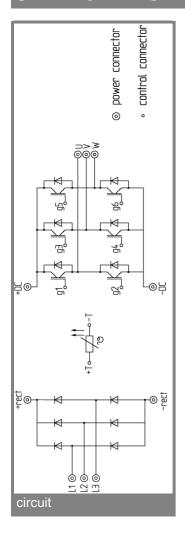


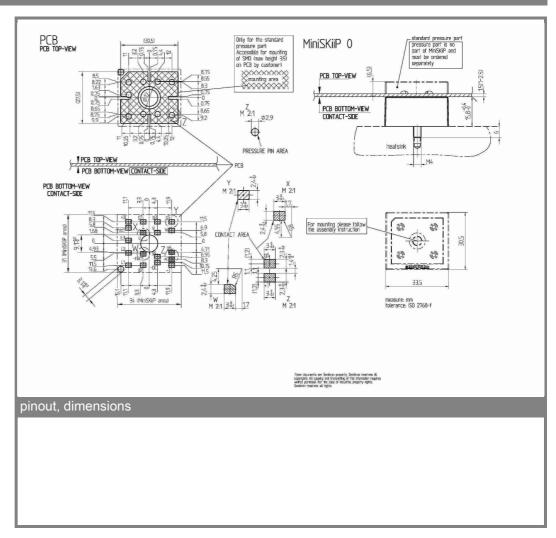












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

<sup>\*</sup> The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.